"RESPONSE UNDER 37 CFR 1.116-
EXPEDITED PROCEDURE EXAMINING
GROUP 2128 "

OBLON

SPIVAK

McCLELLAND

MAIER
&
NEUSTADT

P.C.
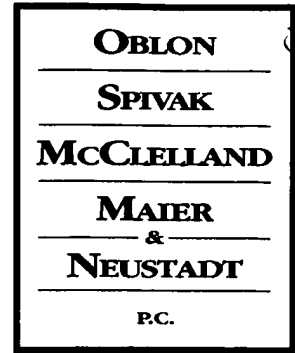
ATTORNEYS AT LAW

Docket No.: 217804US2

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

RE: Application Serial No.: 10/028,319
Applicants: Sanae ITO, et al.
Filing Date: December 28, 2001
For: SIMULATION METHOD, SIMULATION
PROGRAM, AND SEMICONDUCTOR DEVICE
MANUFACTURING METHOD EACH EMPLOYING
BOUNDARY CONDITIONS
Group Art Unit: 2128
Examiner: Gebresilassie, K.K.

SIR:

Attached hereto for filing are the following papers:

REQUEST FOR RECONSIDERATION UNDER 37 CFR §1/116

Our check in the amount of **$0.00** attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.

Eckhard H. Kuesters
Registration No. 28,870

Surinder Sachar
Registration No. 34,423

Customer Number
22850
(703) 413-3000 (phone)
(703) 413-2220 (fax)

DOCKET NO: 217804US2

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF   :

SANAE ITO, ET AL.   : EXAMINER: GEBRESILASSIE, K.K.

SERIAL NO: 10/028,319   :

FILED: DECEMBER 28, 2001   : GROUP ART UNIT: 2128

FOR: SIMULATION METHOD,   :
SIMULATION PROGRAM, AND
SEMICONDUCTOR DEVICE
MANUFACTURING METHOD EACH
EMPLOYING BOUNDARY CONDITIONS

REQUEST FOR RECONSIDERATION UNDER 37 CFR §1.116

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated November 28, 2005, please amend the above-

identified application as follows:

Remarks/Arguments begin on page 2 of this paper.